



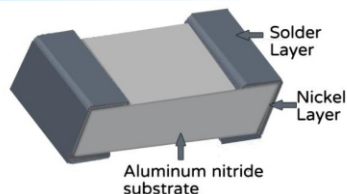
● Features

- High thermal conductivity AlN substrate (170 W/mK)
- Electrically isolated
- Available with lead (Pb)-free wrap terminations
- AlN ceramic chips
- Low capacitance

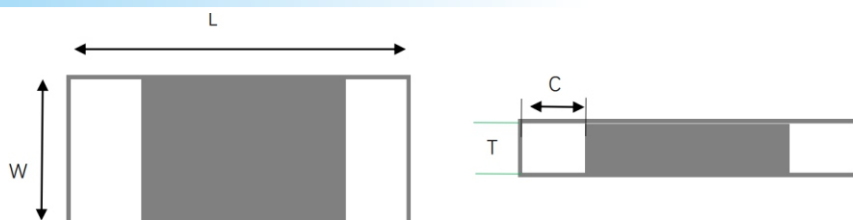
● Application

- Switch mode power supply
- Converters
- RF amplifier

● Construction



● Dimensions



Type	Size (mm)	Item	L	W	C	T
NTJ	1225	Thermal Jumper	3.2 ± 0.20	6.4 ± 0.20	0.50 ± 0.15	0.75 ± 0.15
	2512		6.4 ± 0.20	3.2 ± 0.20	0.50 ± 0.15	0.75 ± 0.15

● Ordering Information

Example

NTJ	2512	06	E
(1)	(2)	(3)	(4)
Type	Size (inch)	Thickness	Packaging

(1)Type:NTJ

(2)Size:1225、2512

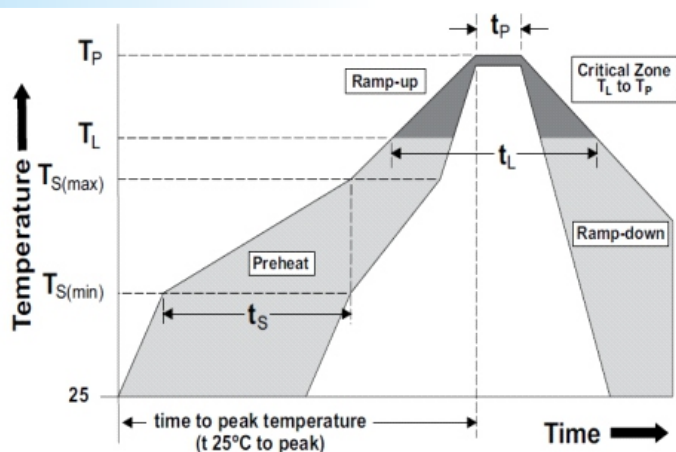
(3)Thickness:06=0.6mm、075=0.75mm

(4)Packaging: E:Plastic ; 1: Q' ty: 1KPcs/Reel、 2:Q' ty: 2KPcs/Reel
3:Q' ty: 3KPcs/Reel、 4:Q' ty: 4KPcs/Reel

● Typical Characteristics

Item Type	Thermal resistance (°C/W), TR	Thermal conductance (mW/°C), TC	Capacitance (pF)@1KHz	Dielectric withstanding voltage kVAC, RMS (60 Hz)	Operating temperature range	Storage temperature range
NTJ (1225)	4	250	1.1	>1.5	-65~+150°C	-65~+150°C
NTJ (2512)	15	67	1.0			

● IR Reflow-Soldering Profile



Reflow Condition		Pb – Free assembly
Pre heat	- Temperature Min ($T_{S(min)}$)	150°C
	- Temperature Max ($T_{S(max)}$)	200°C
	- Time (Min to Max) (t_s)	60 – 120 secs
Average ramp up rate (Liquidus Temp (T_L) to peak)		5°C /second max
$T_{S(max)}$ to T_L - Ramp-up Rate		5°C /second max
- Temperature (T_L) (Liquidus)		217°C
- Time (t_L)		60 – 150 seconds
Peak Temperature (T_P)		260°C
Time within 5°C of actual peak Temperature (t_p)		10 – 30 seconds
Ramp-down Rate		6°C /second max
Time 25°C to peak Temperature (T_P)		8 minutes Max.
Wave Soldering		260°C , 10 seconds max.
Hand Soldering		350°C , 5 seconds max.

● Performance

Item	Requirement	Test Method
Solderability	J-STD-002,method B and B1	Over 95%of termination must be covered with solder.
Resistance to Solder Heat	T=260+/-5°C solder,10+/-1 sec dwell	Without solder leaching
Board Flex	AEC-Q200 Method 005	Without damaged &Crack